

UNIT

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#### SLPS304B-DECEMBER 2010-REVISED JUNE 2012

# 30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17506Q5A

## **FEATURES**

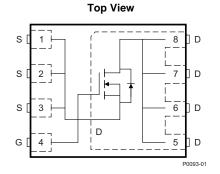
- Ultralow Q<sub>q</sub> and Q<sub>qd</sub> •
- Low Thermal Resistance
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

## **APPLICATIONS**

- Point-of-Load Synchronous Buck in Networking, Telecom, and Computing Systems
- Synchronous or Control FET Applications •

## DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.



#### TYPICAL VALUE $T_A = 25^{\circ}C$ unless otherwise stated Drain to Source Voltage 30

**PRODUCT SUMMARY** 

V <sub>DS</sub>	Drain to Source Voltage 30			
Qg	Gate Charge Total (4.5V) 8.3			
Q <sub>gd</sub>	Gate Charge Gate to Drain 2.3			
D	Drain to Source On Resistance	$V_{GS} = 4.5V$	4.2	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V 3.2		mΩ
V <sub>GS(th)</sub>	Threshold Voltage	1.3	V	

## **ORDERING INFORMATION**

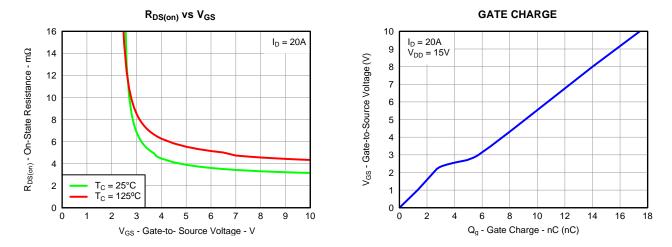
Device	Package	Media	Qty	Ship
CSD17506Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

#### **ABSOLUTE MAXIMUM RATINGS**

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	30	V
$V_{GS}$	Gate to Source Voltage	±20	V
	Continuous Drain Current, T <sub>C</sub> = 25°C	100	А
ID	Continuous Drain Current <sup>(1)</sup>	23	А
I <sub>DM</sub>	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	150	А
PD	Power Dissipation <sup>(1)</sup>	3.2	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, single pulse $I_D = 72A$ , L = 0.1mH, $R_G = 25\Omega$	259	mJ

(1) Typical  $R_{\theta JA} = 39^{\circ}$ C/W on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration ≤300µs, duty cycle ≤2%



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

# CSD17506Q5A

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**KAS TRUMENTS** 

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics				1	
<b>BV</b> <sub>DSS</sub>	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = 250 \mu A$	30			V
I <sub>DSS</sub>	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = 20V$			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	1	1.3	1.8	V
D	Drain to Course On Desistance	$V_{GS} = 4.5V, I_{DS} = 20A$		4.2	5.3	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V, I <sub>DS</sub> = 20A		3.2	4	mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>DS</sub> = 20A		76		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			1270	1650	pF
C <sub>oss</sub>	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz		860	1120	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			50	65	pF
R <sub>G</sub>	Series Gate Resistance			1.1	2.2	Ω
Qg	Gate Charge Total (4.5V)			8.3	11	nC
Q <sub>gd</sub>	Gate Charge Gate to Drain			2.3		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	$V_{\rm DS} = 15V, I_{\rm DS} = 20A$		3.1		nC
Q <sub>g(th)</sub>	Gate Charge at Vth			1.6		nC
Q <sub>oss</sub>	Output Charge	$V_{DS} = 14V, V_{GS} = 0V$		23		nC
t <sub>d(on)</sub>	Turn On Delay Time			7.5		ns
tr	Rise Time	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 4.5V,		13		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$I_{DS} = 20A, R_G = 2\Omega$		13		ns
t <sub>f</sub>	Fall Time			5.3		ns
Diode Cl	haracteristics	· · ·			1	
$V_{SD}$	Diode Forward Voltage	$I_{SD} = 20A, V_{GS} = 0V$		0.8	1	V
Q <sub>rr</sub>	Reverse Recovery Charge			33		nC
t <sub>rr</sub>	Reverse Recovery Time	$V_{DD} = 14V, I_F = 20A, di/dt = 300A/\mu s$		27		ns

## THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			1	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient <sup>(1)(2)</sup>			50	°C/W

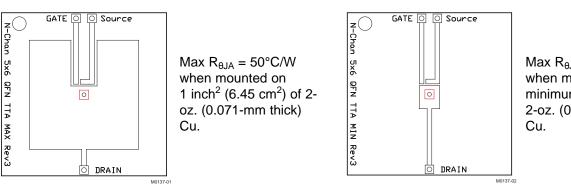
(1) R<sub>θJC</sub> is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R<sub>θJC</sub> is specified by design, whereas R<sub>θJA</sub> is determined by the user's board design.
 (2) Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.



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#### Max $R_{\theta JA} = 120^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

## **TYPICAL MOSFET CHARACTERISTICS**

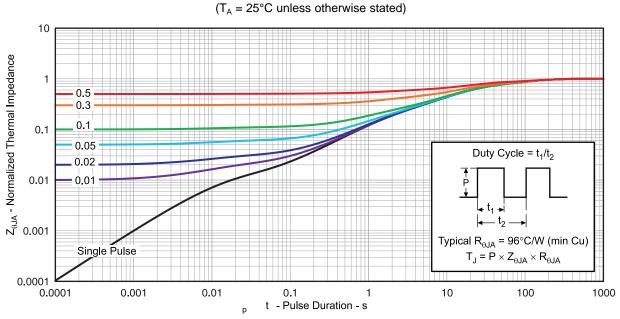


Figure 1. Transient Thermal Impedance

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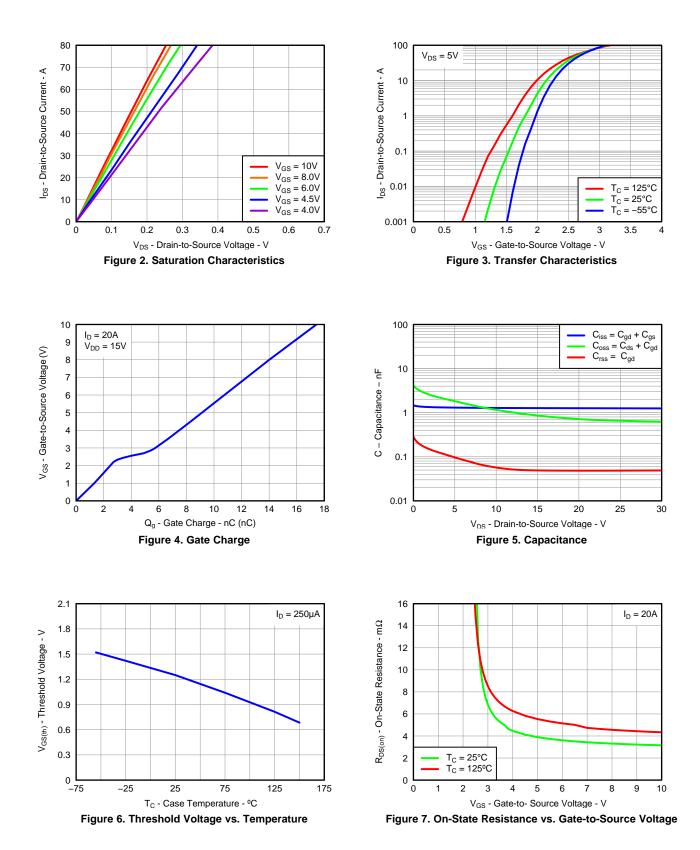
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NSTRUMENTS

Texas

## **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 





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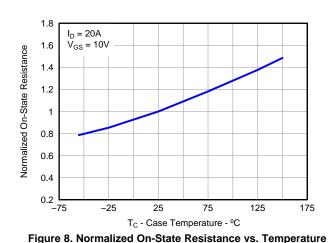
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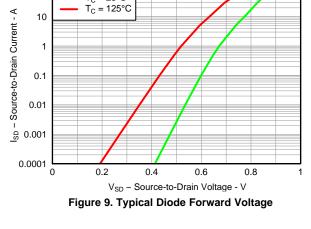
## **TYPICAL MOSFET CHARACTERISTICS (continued)**

100

 $T_C = 25^{\circ}C$ 

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 





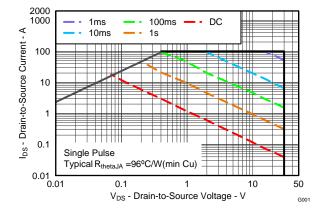


Figure 10. Maximum Safe Operating Area

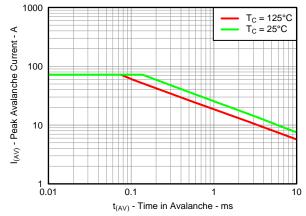
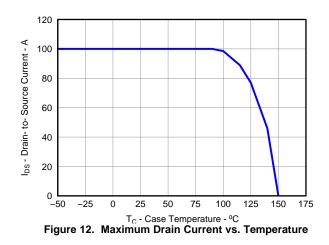


Figure 11. Single Pulse Unclamped Inductive Switching

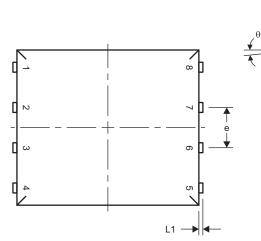


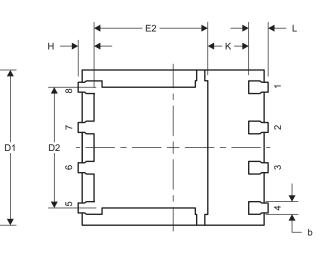
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## **MECHANICAL DATA**

## **Q5A Package Dimensions**

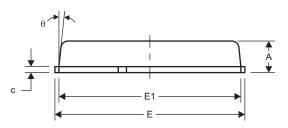




Top View

Side View

Bottom View



#### Front View

M0135-01

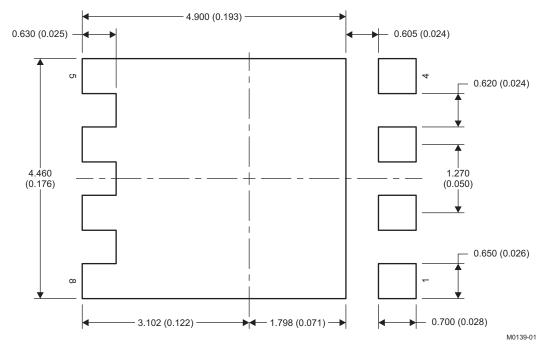
DIM		MILLIMETERS	
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
b	0.33	0.41	0.51
С	0.20	0.25	0.34
D1	4.80	4.90	5.00
D2	3.61	3.81	4.02
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
е	1.17	1.27	1.37
н	0.41	0.56	0.71
К	1.10		
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
θ	0°		12°



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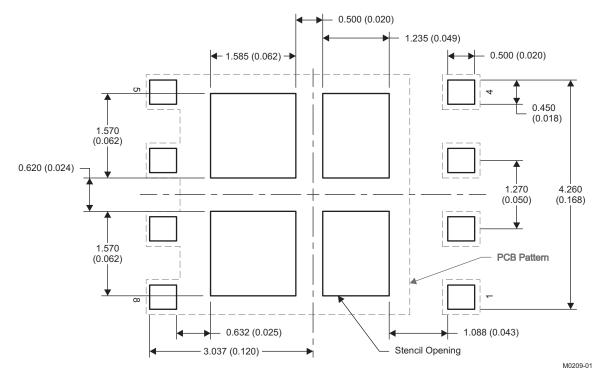
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## **Recommended PCB Pattern**



NOTE: Dimensions are in mm (inches).

### **Stencil Recommendation**

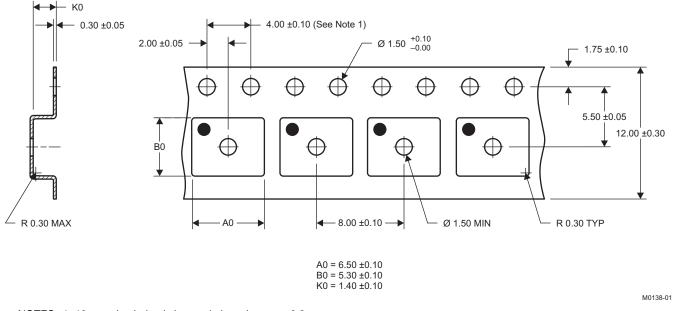


NOTE: Dimensions are in mm (inches).

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

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## **Q5A Tape and Reel Information**



- NOTES: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
  - 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
    - 3. Material: black static-dissipative polystyrene
    - 4. All dimensions are in mm (unless otherwise specified)
    - 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

## **REVISION HISTORY**

Changes from Original (December 2010) to Revision A				
<ul> <li>Changed V<sub>GS</sub> in the Abs Max Ratings table From: +20/-12V To: ±20V</li> <li>Changed from +20/-12V to 20V</li> </ul>				
Changes from Revision A (July 2011) to Revision B	Page			

• Cł	hanged Figure 10, Maximum Safe Operating Area		6
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### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CSD17506Q5A	Active	Production	VSONP (DQJ)   8	2500   LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17506
CSD17506Q5A.B	Active	Production	VSONP (DQJ)   8	2500   LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17506

<sup>(1)</sup> **Status:** For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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